

Switchmode Full Plastic Dual Ultrafast Power Rectifiers

Designed for use in switching power supplies. inverters and as free wheeling diodes. These state-of-the-art devices have the following

Features

- * High Surge Capacity
- *Low Power Loss, High efficiency
- *150°℃ Operating Junction Temperature
- * Low Stored Charge Majority Carrier Conduction
- * Low Forward Voltage, High Current Capability
- * High-Switching Speed Recovery Time
- * Plastic Material used Carries Underwriters Laboratory
- * Flammability Classification 94V-O
- * Pb free
- * In compliance with EU RoHs directives



MAXIMUM RATINGS

Characteristic	Symbol	URF2040C	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	400	V
RMS Reverse Voltage	V _{R(RMS)}	280	V
Average Rectifier Forward Current Total Device (Rated V _R),T _C =100°C	I _{F(AV)}	10 20	А
Peak Repetitive Forward Current (Rate V _R , Square Wave, 20kHz)	I _{FM}	20	А
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions half-wave, single phase, 60Hz)	I _{FSM}	160	А
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-65 to +150	°C

ELECTRICAL CHARACTERISTICS

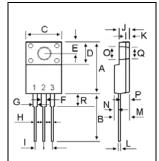
Characteristic	Symbol	Min.	Тур.	Max.	Unit
Maximum Instantaneous Forward Voltage ($I_F = 10 \text{ Amp } T_C = 25^{\circ}C$) ($I_F = 10 \text{ Amp } T_C = 125^{\circ}C$)	V _F		1.15 0.97	1.40 	V
Maximum Instantaneous Reverse Current (Rated DC Voltage, T _C = 25℃) (Rated DC Voltage, T _C = 125℃)	I _R		0.02 5	10 	uA
Reverse Recovery Time ($I_F = 0.5 \text{ A}$, $I_R = 1.0$, $I_{rr} = 0.25 \text{ A}$)	T _{rr}		25	50	ns
Typical Junction Capacitance (Reverse Voltage of 4 volts & f=1 MHz)	CP		63		₽F

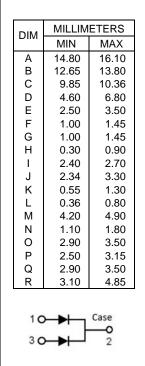
URF2040C

ULTRA FAST RECTIFIERS

20 AMPERES 400 VOLTS









URF2040C

FIG-3 FORWARD CURRENT DERATING CURVE

LEAD TEMPERATURE (°C)

FIG-4TYPICAL JUNCTION CAPACITANCE

100

125

f = 1 M H z a = 25т

C

20

16

12

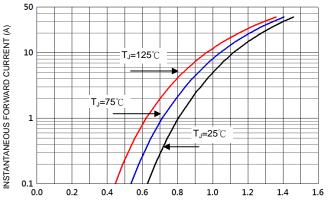
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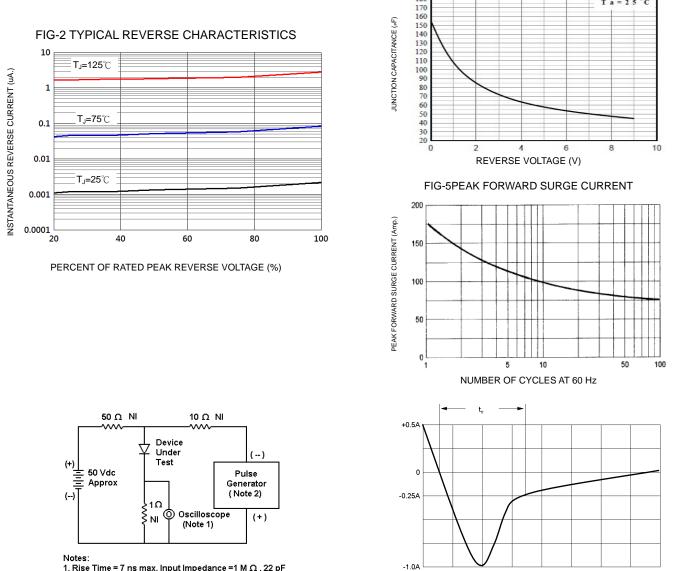
200 190 180

AVERAGE FORWARD RECTIFIED CURRENT (Amp.)

FIG-1 TYPICAL FORWARD CHARACTERISTICS



FORWARD VOLTAGE (V)



1. Rise Time = 7 ns max. Input Impedance =1 M Ω , 22 pF 2. Rise Time = 10 ns max. Input Impedance = 50Ω

> Set time base for 10/20 ns/cm FIG-6 Reverse Recovery Time Characteristic and Test Circuit Diagram



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